

# PCIe® Gen 3 NVMe M.2 2280 / 2242 / 2230 SSD

The Global Leader in Specialized Storage and Memory Solutions





### **Key Features**

- MCU-based Power Loss Protection Design with Level 4 (data-in-flight) protection\*
- Self-Encrypting Drive (SED) with AES 256-bit encryption, TCG Opal 2.0 \*
- Thermal Heatsink Solutions\*\*

End-to-End Data Path ProtectionTRIM function support

\* May vary by product and project support \*\* Customization available on a project basis.

M.2 solid state modules based on the NVMe<sup>™</sup>protocol leverage the blazing-fast PCI Express<sup>®</sup> (PCIe<sup>®</sup>) interface to deliver dramatic improvements in speed and performance to fulfill the increasing demand for responsiveness in enterprise storage systems and to support the growing data-hungry needs of today's enterprise. Delivering 32 Gb/s bandwidth on a PCIe 3.1 x4 slot (8 Gb/s per Iane), ATP NVMe SSDs outperform Serial ATA 6 Gb/s SSDs with 4-6X faster access, over 3X lower latency, and higher Input/Output per Second (IOPS). ATP NVMe SSDs with industrial operating temperature rating deliver stable performance even in extreme temperatures ranging from -40°C to 85°C, while Dynamic Thermal Throttling automatically adjusts the speed to maintain cooler operation under intense and heavy workloads.

Adopting NVMe 1.3 specifications and integrating 3D NAND TLC technology, ATP's M.2 2280 NVMe modules offer up to 1.92TB of storage capacity and deliver boosted performance with sequential read up to 3,420 MB/s, sequential write up to 3,050 MB/s, and random read/write IOPS up to 225,200/179,200.

Designed to move past the limitations of mechanical drives, NVMe was specifically built from the ground up for faster, more efficient access to storage devices with non-volatile memory such as current NAND flash solutions and future non-volatile memory technologies. These SSDs can deliver fast, reliable and durable performance for any demanding application.

**PRODUCT FLYER** | PCIe<sup>®</sup> Gen 3 NVMe M.2 2280 / 2242 / 2230 SSD



### Specifications

			PCle <sup>®</sup> Gen 3	3 NVMe M.2	2280/	2242 / 22	30 SSD					
Product Line	 N750Pi		N700Pi	N700		N700Sc	N650		650Sc	N600	)Si	 N600Sc
Interface			1170011	11700	PCIe G3:		11050		05050	i noot		NOODL
Flash Type	3D T	LC (pSLC m	iode)	3D	TLC (pSLC	mode)			3D <sup>-</sup>	TLC		
Form Factor	M.2 2280-D2-M		Γ	M.2 2230-S4-M			M.2 2280-D2-M					
Operating Temperature (Tcase) <sup>1</sup>	-40°C to 85°C		-40°C to	-40°C to 85°C 0°C to 70°C		-40°C to	85°C 0°C	to 70°C	-40°C to	0 85°C	0°C to 70°C	
Power Loss Protection Options	Hardwar	e + Firmwa	re Based	F	irmware B	ased	Ha	rdware + Firm	iware Base	ed or Firmw	vare Base	d
Optional SED Features				AES 256-bi	t Encryptic	n, TCG Opal	2.0					
Capacity	40 GB to 320 (	GB 4	0 GB to 640 GE	3 4	0 GB to 16		1	120 GB to 960	GB	12	0 GB to 3.	84 TB
		2 150			Performa							
Sequential Read (MB/s) up to	3,150			2,000			3,420					
Sequential Write (MB/s) up to	2,670	2,670 2,820 1,600		3,050								
Random Reads IOPS up to Random Writes IOPS up to		147,789 114,227			135,600		176,600			179,200		
Random Writes IOPS up to		114,227		Endu	112,000 rance and l			176,600			179,200	J
Endurance (TDM/) <sup>2</sup> up to	16.000 TB		21,300 TB	Liidu	4,280 T	,		4,640 TB			10,600 1	в
Endurance (TBW) <sup>2</sup> up to Reliability MTBF @ 25°C	10,000 TB		21,50010		2,000,000			4,040 TB			10,000 1	5
					000,000 Others							
Dimensions (mm)	80.0 x 22.0 x 3.5 (N 80.0 x 24.4 x 12.5			ink)	30.0 x 22.0			30.0 x 22.0 x 3. 30.0 x 24.4 x 1				sink)
Certifications		(	CE, FCC, BSMI, U	JKCA, RoHS, R	EACH		CE, FCC, BSM	I, UKCA, RoHS, and	d REACH are a	available for S	SD models v	<i>i</i> ith capacities 3.84 TB SSD model.
Warranty		5 years					between 120	2 years			induction of the	5.04 TD 550 Model.
DCLo	° Gen 3 NVMe I	חסרר ר וו	/ 77/.7 / 77									
	Gen S NVMEr	vi.z zzou		lue								
Product Line	N600Vc		N600Vc	N600	Vi	N600\	Vc					
Interface				G3 x4								
Flash Type				TLC								
Form Factor	M.2 2280 52-M		2242 D5-M		M.2 2230-							
Operating Temperature (Tcase) <sup>1</sup>	0.	°C to 70°C	<b>F</b> :	-40°C to	85°C	0°C to 7	0°C					
Power Loss Protection Options Optional SED Features			Firmwa	re Based								
Capacity	120 G	B to 960 GE	3		120GB to	480GB						
capacity	120 0	D 10 900 01	Perfor	mance	12000 00	40000						
Sequential Read (MB/s) up to		2,600			2,050							
Sequential Write (MB/s) up to		1,870			1,550							
Random Reads IOPS up to		184,300			138,00	0						
Random Writes IOPS up to		145,900			112,60	0						
			Endurance	and Reliability								
Endurance (TBW) <sup>2</sup> up to	1	,520 TB			768 TE	3						
Reliability MTBF @ 25°C			>2,000,0	00 hours								
			Ot	hers								
Dimensions (mm)	80.0 x 22.0 x 2.2	2 42.0	) x 22.0 x 3.6	2.	30.0 x 22.0	) x 2.5						
Certifications		C	E, FCC, BSMI, U	KCA, RoHS, RE	ACH							
Warranty				/ears								
			- 1	cuis								
		A	<u>∽</u>   û	<u>.</u> 1 (2)		\$  <u>-</u> 0 <u>-</u>	L L	<u>م ار</u> ژر	3	W		Con S
Technologies & Add-On Services		erl Harriware hasor	،   کَتْ کَ	$\Delta \mid \heartsuit$	End-to-End				al Industrial			Hus
	S.M.A.R.T. Firmware-bas Power Loss Protection	Power Loss Protection	AutoRefresh Lev	ed Wear Dynamic Dat eling Refresh	a End-to-End Data Path Protection	Auto-Read Calibration	ecure Erase TCG O	pal 2.0 Dynamic Therm Throttling	al Industrial Temperature	Anti-Sulfur Resistors	Conformal Coating	Joint Validation
Premium	0 0	0	0	0 0	0	0	<b>A</b>	- c	0			-
PCle <sup>®</sup> Gen3 NVMe M.2 2280 / 2242 / 2230 Superior	0 0	0	0	0 0	0	0	<b>A</b> (	- c				-
Value	0 0	-	0	0 0	0	0			-			-
PCle <sup>®</sup> Gen3 NVMe M.2 2280 SSD ( 3.84 TB Model ) Superior	0 0	-	0	0 0	0	0		0	0	-		

1 Case Temperature, the composite temperature as indicated by SMART temperature attributes.
2 Under highest Sequential write value. May vary by density, configuration and applications.
A: Customization option available on a project basis.

Hot Items Ordering Information								
Product Line	Capacity <sub>1</sub>	Operating Temperature <sub>2</sub>	Power Loss Protection <sub>3</sub>	SED <sub>4</sub>	P/N			
N650Si	120GB	-40°C to 85°C	Hardware + Firmware Based	-	AF120GSTJA-8BCIP			
N650Si	240GB	-40°C to 85°C	Hardware + Firmware Based	-	AF240GSTJA-8BCIP			
N650Si	480GB	-40°C to 85°C	Hardware + Firmware Based	-	AF480GSTJA-8BCIP			
N650Si	960GB	-40°C to 85°C	Hardware + Firmware Based	-	AF960GSTJA-8BCIP			
N650Sc	120GB	0°C to 70°C	Hardware + Firmware Based	-	AF120GSTJA-8BCXP			
N650Sc	240GB	0°C to 70°C	Hardware + Firmware Based	-	AF240GSTJA-8BCXP			
N650Sc	480GB	0°C to 70°C	Hardware + Firmware Based	-	AF480GSTJA-8BCXP			
N650Sc	960GB	0°C to 70°C	Hardware + Firmware Based	-	AF960GSTJA-8BCXP			
N600Sc	120GB	0°C to 70°C	Hardware + Firmware Based	-	AF120GSTJA-8BAXP			
N600Sc	240GB	0°C to 70°C	Hardware + Firmware Based	-	AF240GSTJA-8BAXP			
N600Sc	480GB	0°C to 70°C	Hardware + Firmware Based	-	AF480GSTJA-8BAXP			
N600Sc	960GB	0°C to 70°C	Hardware + Firmware Based	-	AF960GSTJA-8BAXP			
N600Sc	1920GB	0°C to 70°C	Hardware + Firmware Based	-	AF1T92STJA-8BAXP			
N600Sc	120GB	0°C to 70°C	Firmware Based	-	AF120GSTJA-8BAXX			
N600Sc	240GB	0°C to 70°C	Firmware Based	-	AF240GSTJA-8BAXX			
N600Sc	480GB	0°C to 70°C	Firmware Based	-	AF480GSTJA-8BAXX			
N600Sc	960GB	0°C to 70°C	Firmware Based	-	AF960GSTJA-8BAXX			
N600Sc	1920GB	0°C to 70°C	Firmware Based	-	AF1T92STJA-8BAXX			
N600Vc (M.2 NVMe 2280)	120GB	0°C to 70°C	Firmware Based	-	AF120GSTJA-DBCXX			
N600Vc (M.2 NVMe 2280)	240GB	0°C to 70°C	Firmware Based	-	AF240GSTJA-DBCXX			
N600Vc (M.2 NVMe 2280)	480GB	0°C to 70°C	Firmware Based	<u>.</u>	AF480GSTJA-DBCXX			
N600Vc (M.2 NVMe 2242)	120GB	0°C to 70°C	Firmware Based	-	AF120GSTJC-DBBXX			
N600Vc (M.2 NVMe 2242)	240GB	0°C to 70°C	Firmware Based	-	AF240GSTJC-DBBXX			
N600Vc (M.2 NVMe 2242)	480GB	0°C to 70°C	Firmware Based	-	AF480GSTJC-DBBXX			
N600Vc (M.2 NVMe 2242)	960GB	0°C to 70°C	Firmware Based	-	AF960GSTJC-DBBXX			

1 Amount of actual usable storage that can be utilized.

2 Refers to Case Temperature range during device operation, as indicated by SMART temperature attributes.

3 Hardware + Firmware-based power loss protection design with Level 4 (data-in-flight) protection; Firmware-based power loss protection design with Level 1 (data-at-rest) protection.

4 Allows data written to and read from the SSD to be constantly and automatically encrypted and decrypted. Conforms to TCG Opal 2.0 and uses AES 256-bit HW encryption.

Product spec and its related information are subject to change without advance notice. Please refer to <u>www.atpinc.com</u> for latest information

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